NSN 5961-01-029-7203

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-029-7203 **Inclosure Material:** Glass **Overall Length:** Between 0.230 inches and 0.300 inches **Overall Diameter:** Between 0.085 inches and 0.107 inches **Mounting Method: Terminal Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 25.0 reverse voltage, peak **Current Rating Per Characteristic:** 100.00 milliamperes forward current, average **Power Rating Per Characteristic:** 80.0 milliwatts small-signal input power, common-collector peak **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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